MSKSEMI 美森科













ESD

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B110WS

Product specification





FEATURES

- Guard ring protection.
- Low forward voltage drop.
- For use in low voltage, high frequency inverters.
- High surge current capability.

APPLICATIONS

- Low voltage rectification
- Reverse polarity protection
- Low power consumption applications

Reference News

PACKAGE OUTLINE	Circuit	Marking
	-	110s
SOD-323		



Absolute Maximum Ratings(Ta=25 $^{\circ}$ C)

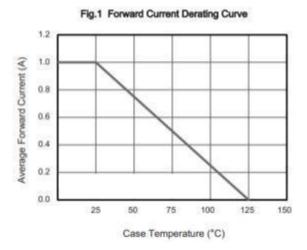
Symbol	Parameter	Limit	Unit
VRRM	Maximum Recurrent Peak Reverse Voltage	100	V
VRMS	Maximum RMS Voltage	70	V
VDC	Maximum DC Blocking Voltage	100	V
l _F	Continuous ForwardCurrent	1	Α
İfsm	Non-repetitive Peak Forward Surge Current@8.3mS	25	А
P _{tot}	Total Power Dissipation	250	W
Rөja	Thermal Resistance From Junction To Ambient	400	°C/W
TJ	Operation Junction Temperature Range	-40~+ 125	${\mathbb C}$
Тѕтѕ	Storage Temperature Range	-55~+ 150	$^{\circ}$

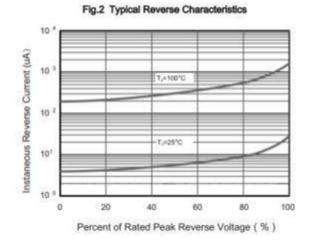
Electrical Characteristics (Ta=25℃ unless otherwise specified)

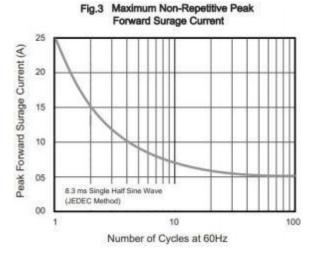
Symbol	Parameter	Test conditions	Min	Тур	Max	Unit
VF	Forward voltage(1)	I _F =1A			0.85	V
l _R	Reverse voltage leakage current	V _R =100V		0.5	2.0	А



Typical Characteristics

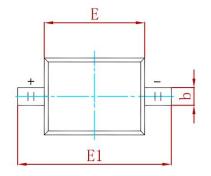


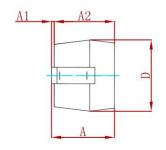


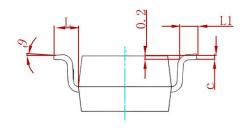




PACKAGE MECHANICAL DATA

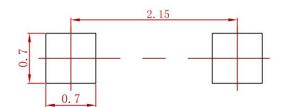






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
Α		1.000		0.039	
A1	0.000	0.100	0.000	0.004	
A2	0.800	0.900	0.031	0.035	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	1.200	1 .400	0.047	0.055	
E	1.600	1 .800	0.063	0.071	
E1	2.550	2.750	0.100	0.108	
L	0.475	REF.	0.019	REF.	
е	0°	8 [?]	0.	8 [:]	

Suggested Pad Layout



Note:

- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
B110WS	SOD-323	3000



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